SKNa 102

Stud Diode

Avalanche Diode

SKNa 102

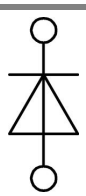
Publish Data

Features

- Avalanche type reverse characteristic
- Reverse voltages up to 5000 V
- Hermetic metal case with ceramic insulator and extra long creepage distances
- Threaded stud ISO M12
- Cooling via heatsinks
- SKN: Anode to stud

Typical Applications

- High voltage rectifier diode for traction and heavy duty applications
- Series connections for high voltage applications
- Non-controllable and half-controllable rectifiers
- Free-wheeling diodes



SKN

$V_{(BR)min}$ V	I_{FRMS} = 200 A (maximum value for continuous operation) I_{FAV} = 125 A (sin. 180; T_c = 80 °C)	C_{max} µF	R_{min} Ω
3600	SKNa 102/36		
4000	SKNa 102/40		
4200	SKNa 102/42		
4500	SKNa 102/45		
4600	SKNa 102/46		
4800	SKNa 102/48		
5000	SKNa 102/50		

Symbol	Conditions	Values	Units
I_{FAV}	sin. 180 ; T_c = 80 (102) °C	125 (100)	A
I_D	K 1,1; T_a = 45 °C; B2 / B6	114 / 162	A
	K 1,1F; T_a = 35 °C; B2 / B6	189 / 266	A
I_{FSM}	T_{vj} = 25 °C; 10 ms	1900	A
	T_{vj} = 160 °C; 10 ms	1600	A
i^2t	T_{vj} = 25 °C; 8,3 ... 10 ms	18000	A^2s
	T_{vj} = 160 °C; 8,3 ... 10 ms	12500	A^2s
V_F	T_{vj} = 25 °C; I_F = 300 A	max. 1,9	V
$V_{(TO)}$	T_{vj} = 150 °C	max. 1	V
r_T	T_{vj} = 150 °C	max. 3,7	mΩ
I_{RD}	T_{vj} = 25 °C; V_{RD} = $V_{(BR)min}$	max. 1000	µA
	T_{vj} = 160 °C; V_{RD} = $V_{(BR)min}$;	max. 15	mA
P_{RSM}	T_{vj} = 160 °C; t_p = 10 µs	36	kW
$R_{th(j-c)}$		0,3	K/W
$R_{th(c-s)}$		0,08	K/W
T_{vj}		- 40 ... + 160	°C
T_{stg}		- 40 ... + 160	°C
V_{isol}		-	V~
M_s	to heatsink	10	Nm
		90	lb.in.
a		5 * 9,81	m/s^2
m	approx.	110	g
Case		E 44	

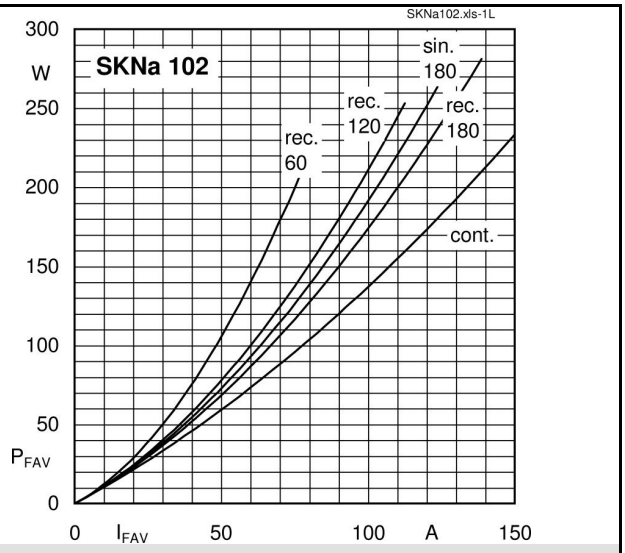


Fig. 1L Power dissipation vs. forward current

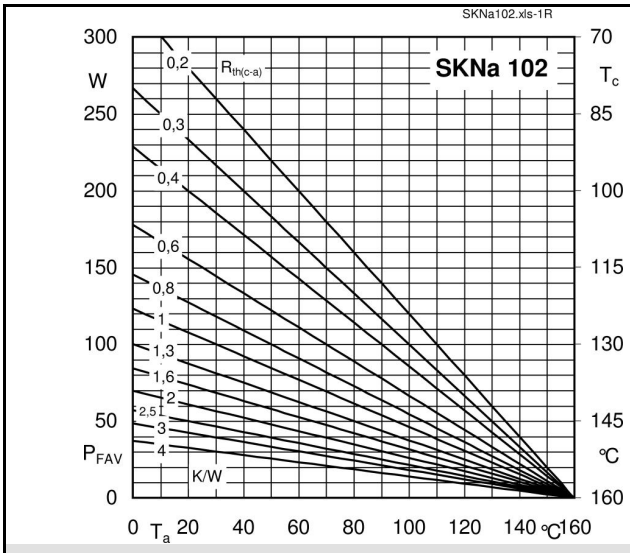


Fig. 1R Power dissipation vs. ambient temperature

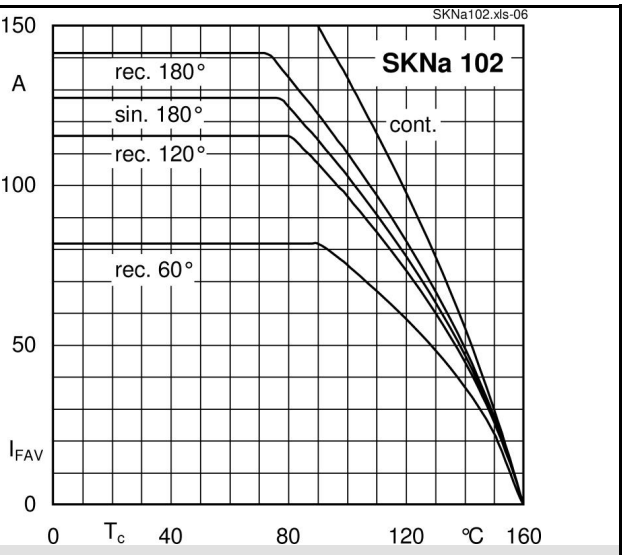


Fig. 2 Forward current vs. case temperature

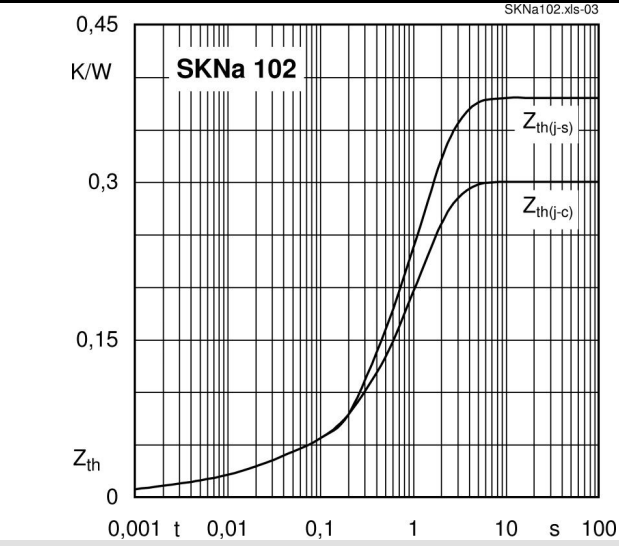


Fig. 4 Transient thermal impedance vs. time

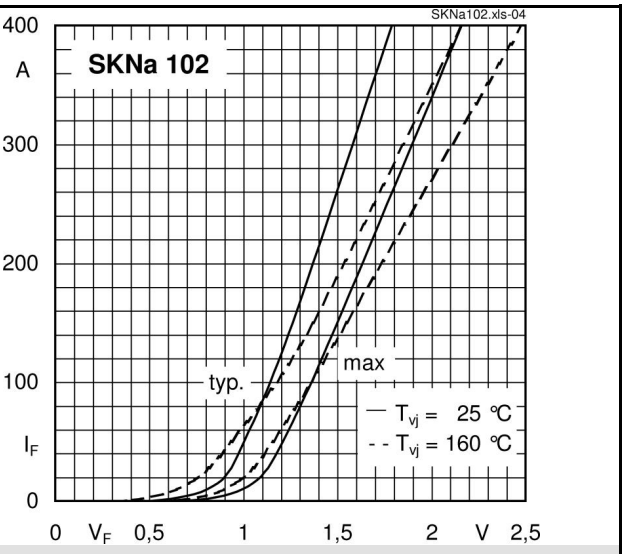


Fig. 5 Forward characteristics

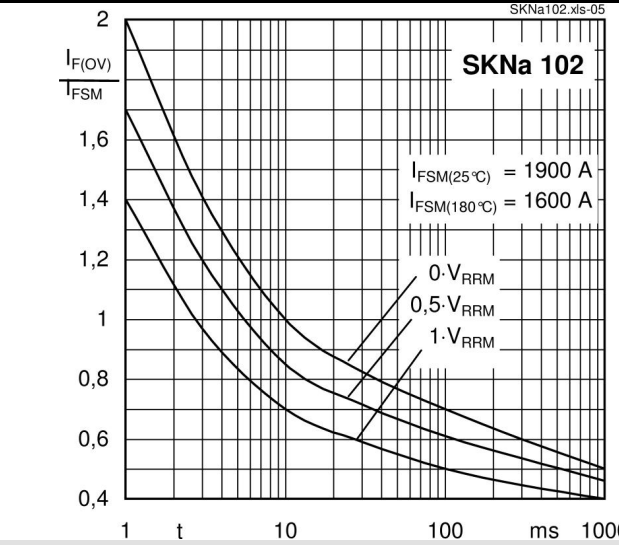
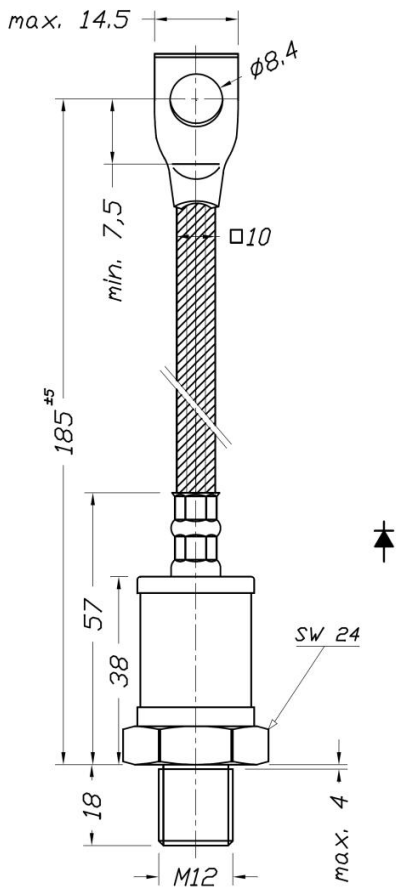


Fig. 6 Rated surge overload current vs. time

Dimensions in mm



CASE E 44 (IEC 60191: A 9 MA modified)

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